



Correct as of 13-Mar-2025 7:51pm For the latest version of our agenda, visit csinternational.net

## Day 1 - Monday 7th April 2025

18:30 Pre-conference networking drinks reception

## Day 2 - Tuesday 8th April 2025

08:00 Registration and welcome refreshments 08:50 Housekeeping by Chris Meadows and Tim Bettles - Conference Chairs Expanding the emission envelope Expanding the Spectral Range of GaN-based SLEDs 09:00 Presented by Marco Malinverni - Exalos Perfecting GaN VCSEL Production Process 09:15 Presented by Tetsuya Takeuchi - Meijo University Connected Metrology for Growth and Characterization of InP and GaAs Laser Structures - from Epi to Etch 09:30 Presented by Iris Claussen - LayTec AG Germanium as an Enabler for Large Volume Production in PV and Photonics 09:45 Presented by Ivan Zyulkov - Umicore InP NIR VCSELs from 1.3 Im to beyond 2 Im for Single Mode and Multi Mode Applications 10:00 Presented by Christian Neumeyr - Vertilas The Power of Pseudomorphic Nitrides 10:15 Presented by Leo Schowalter - Lit Thinking 10:30 Morning Break GaN: Going beyond fast charging Achieving Avalanche in GaN-on-silicon Diodes 11:10 Presented by Farid Medjdoub - University of Lille Characterizing GaN: Challenges and Advances in Next-Generation Semiconductor Metrology 11:25 Presented by Áron Pekker - Semilab X-ray Metrology Solutions for Compound Semiconductors from Labs to Fabs. 11:40 Presented by Assunta Vigliante - Rigaku AIXTRON Leading Epitaxy Solutions for High Volume Manufacturing of GaN-based Power Devices 11:55 Presented by Dr. Nicolas Muesgens - Aixtron Enhancing Analytical Accuracy of Active Epilayers in Compound Semiconductors by Multi-ion Species Plasma-FIB and Novel 12:10 STEM Techniques Presented by Antonio Mani - Thermo Fisher Scientific GaN's Takeover: The Next Big Leap in Power Electronics 12:25 Presented by Ezgi Dogmus - Yole Group 12:40 Lunch Break Harnessing the Underestimated Potential of GaN in the Digitalization Revolution: A Catalyst for Unforeseen Innovation in 14:10 **Energy Efficiency** Presented by Roberto Crisafulli - STMicroelectronics Epitaxial GaN Growth using MBE for the Development of Next-Generation Devices 14:25 Presented by Romain Bruder - Riber VECTOR: Advancing SEM Metrology with Automation and Versatility 14:40 Presented by Amanda Wscieklica - Raith Driving Adoption of GaN for Power Electronics via 300mm Technology 14:55 Presented by Rudy Parekh - Veeco Advancement in X-Ray Metrology for High Volume Manufacturing of GaN Based Power Devices 15:10 Presented by Qian Zheng - Bruker 15:25 Afternoon Break Maintaining momentum for the microLED Perfecting the Polychromatic Pixel 16:05 Presented by Michelle Chen - Q-Pixel Inc MicroSolid Printing: Redefining the Future of MicroLED Displays 16:20 Presented by Reza Chaji - Vue Real Leveraging NIL for ILED Lens Packaging 16:35 Presented by Thomas Achleitner - EV Group The Future of MicroLED Displays: Which Applications Are Leading in 2025? 16:50 Presented by Raphaël Mermet-Lyaudoz - Yole Group Pioneering Mass Production and Commercialisation of MicroLED Microdisplays for AR 17:05 Presented by Kunal Kashyap - Porotech Revolutionising microLED Displays with Nanowires 17:20 Presented by Pierre Tchoulfian - Aledia

17:35 Closing Remarks

18:30 Networking Drinks / Dinner Reception

## Day 3 - Wednesday 9th April 2025

08:00 Registration and welcome refreshments 08:50 Housekeeping by Chris Meadows and Tim Bettles - Conference Chairs **Optimising opportunities for SiC success** 20 Years of SiC Innovation Leadership: Trench-Assisted Planar Gate Technology 09:00 Presented by Llewellyn Vaughan-Edmunds - Navitas Solving Challenges in Compound Semiconductors: An Equipment Supplier's Perspective 09:15 Presented by David Britz - Applied Materials Building the World's Biggest SiC Fab 09:30 Presented by Peter Friedrichs - Infineon Integrated Metal Etch and Photoresist Strip Solution for SiC Manufacturing 09:45 Presented by Bernhard Hammerl - Siconnex Customized Solutions GmbH High Sensitivity & Throughput Defect Inspection Technologies for SiC and GaN Power Technologies 10:00 Presented by Mike Rosa - Onto Innovation SCREEN's Sustainable Cost-of-Ownership (CoO) Portfolio for Wafer Inspection and Thickness Measurement Tools and HVM 10:15 experience Presented by Alessandro Rossi - SCREEN SPE 10:30 Morning Break **Presentation by Nanotronics** 11:10 Presented by Marius Fischer - Nanotronics **PVA TePla Metrology Solutions for Compound Semiconductors** 11:25 Presented by Frédéric Falise - PVA TePla AG, and Michael Schöler - PVA TePla AG How Artificial Intelligence Heralds the New Era of Wafering 11:40 Presented by Malte Mueller - Lapmaster Wolters Crystal Orientation for Optimizing Quality and Yield throughout the Process Chain 11:55 Presented by Dirk Kok - Malvern Panalytical How to save process cost in your SiC/GaN production using best in class power supplies? 12:10 Presented by Yannick Schneider - TRUMPF 12:25 Lunch Break Ultra-wide bandgap materials: The ultimate devices Sponsored by Precision Fabricators Prospects of Jultra) Wide Randgan Ovide ICs

| 13:55 | Presented by Xiaohang Li - KAUST   |  |  |
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| 14:10 | A Solution to Doping AlN Enabling a New Era of Nitride Semiconductors  Presented by Alan Doolittle - Georgia Institute of Technology                   |  |  |
| 14:25 | Electric Field Engineering to Unlock the Potential of Gallium Oxide Power Devices  Presented by Nolan Hendricks - AFRL (Air Force Research Laboratory) |  |  |
| 14:40 | Efficient Diameter Enlargement of Bulk AlN Presented by Carsten Hartmann - Leibniz-Institut für Kristallzüchtung (IKZ)                                 |  |  |
| 14:55 | The promise of cubic Boron Nitride (c-BN)  Presented by Siddha Pimputkar - Lehigh University   |  |  |
| 15:10 | Closing Remarks  |  |  |



## **NOTES**